NSN 5962-01-120-5241



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-120-5241 **Body Length:** Between 0.755 inches and 0.785 inches **Body Width:** 0.280 inches **Body Height:** Between 0.165 inches and 0.210 inches **Maximum Power Dissipation Rating:** 400.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 5820-01-108-9658 20183 **Features Provided:** Hermetically sealed and w/enable and w/open collector and programmable and programmed **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.5 volts output logic low and 5.5 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a

Demilitarization:

Unit Of Measure:

Yes - demil/mli

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